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EUROPEAN PATENT APPLICATION

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- (54) Method of fabrication of an infrared radiation detector and more particularly an infrared sensitive bolometer
- (57) A method of fabricating an infrared sensitive bolometer, comprising the steps of:
- forming a sacrificial layer (11, 12 or 43) on a substrate (10 or 41);
- patterning said sacrificial layer (11, 12 or 43);
- depositing or growing a layer (13 or 42) consisting essentially of polycrystalline SiGe on said sacrificial layer;
- depositing an infrared absorber (49) on said polycrystalline SiGe layer;
- removing the sacrificial layer (11, 12 or 43).

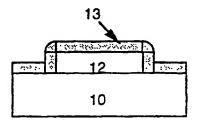


FIG. 1b



EUROPEAN SEARCH REPORT

Application Number EP 98 87 0058

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Place of search THE HAGUE 24 August 1998		Vic	Examiner Sscher, E	
	ATEGORY OF CITED DOCUMENTS	T : theory or principle		
X : part Y : part doct A : tech O : non	cicularly relevant if taken alone icularly relevant if combined with anot ument of the same category inological background -written disclosure rmediate document	E : earlier patent doc after the filing dat her D : document cited in L : document cited fo	cument, but public en the application or other reasons	ished on, or

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EUROPEAN SEARCH REPORT

Application Number EP 98 87 0058

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